

Class 11: Transmission Gates, Latches

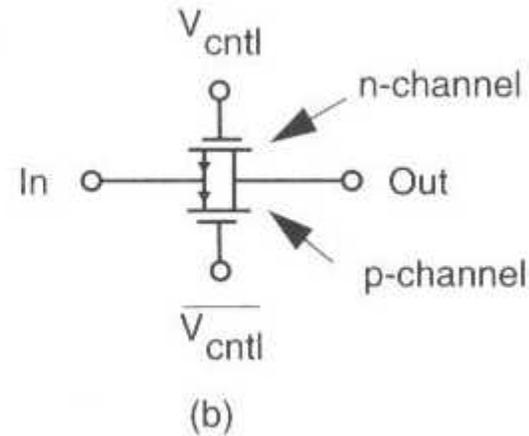
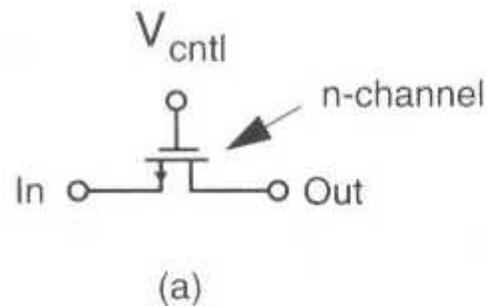
Topics:

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3. X-Gate 2-to-1 MUX
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5. X-Gate 8-to-1 MUX
6. X-Gate Logic Latch
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Transmission Gates (Martin, c5.1)

- Pass Transistors, a.k.a., Transmission Gates are same as a relay
- Why? Usually allows for a reduction in number of transistors



NMOS

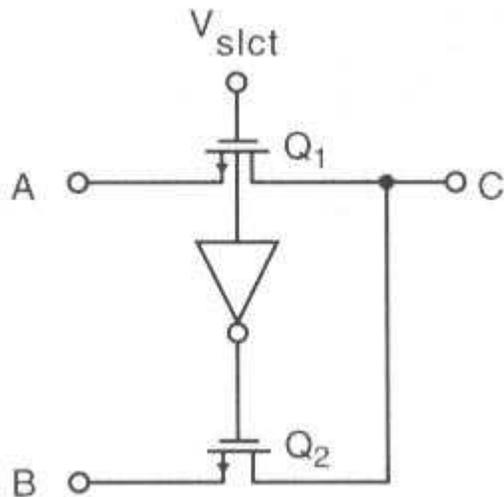
Vcntl	H	L
Out	In	Z

CMOS

Vcntl	H	L
Vcntl'	L	H
Out	In	Z

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Transmission Gate 2-to-1 MUX (Martin, c5.1)



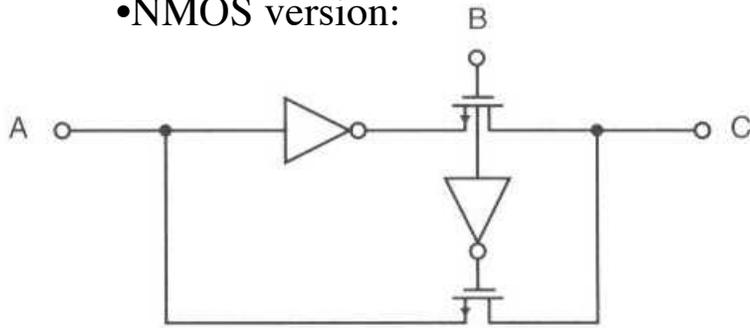
Vslct	A	B	Q1(n)	Q2(n)	C
0	0	0	off	on	B
0	0	1	off	on	B
0	1	0	off	on	B
0	1	1	off	on	B
1	0	0	on	off	A
1	0	1	on	off	A
1	1	0	on	off	A
1	1	1	on	off	A

This same design will be revisited shortly for an 8-to-1 MUX

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Transmission Gate XOR (Martin, c5.1)

- XOR similar to 2-to-1 MUX
- NMOS version:



B	A	Q1(n)	Q2(n)	C
0	0	off	on	0 (A)
0	1	off	on	1 (A)
1	0	on	off	1 (A')
1	1	on	off	0 (A')

- CMOS version:

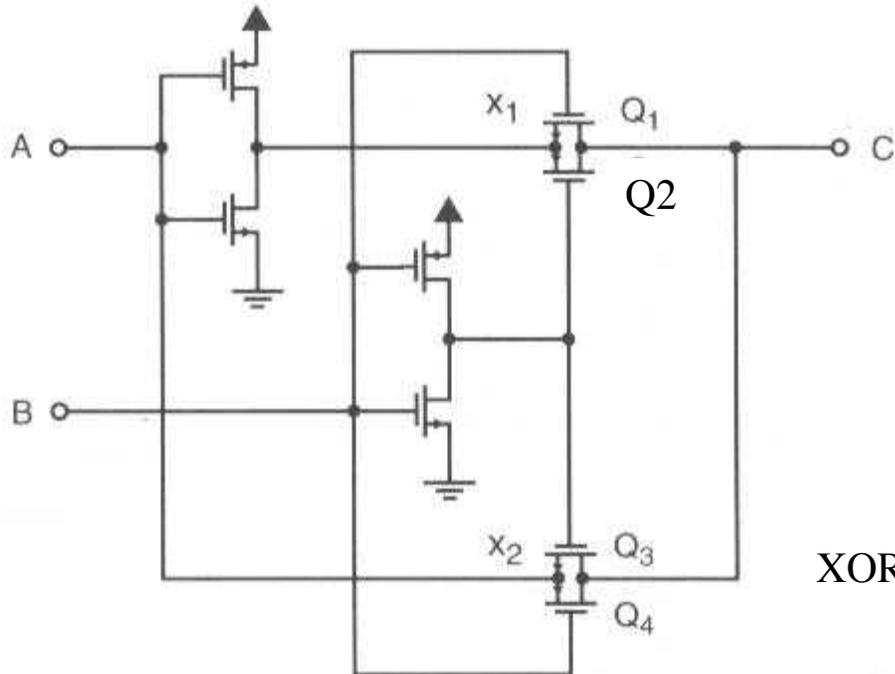


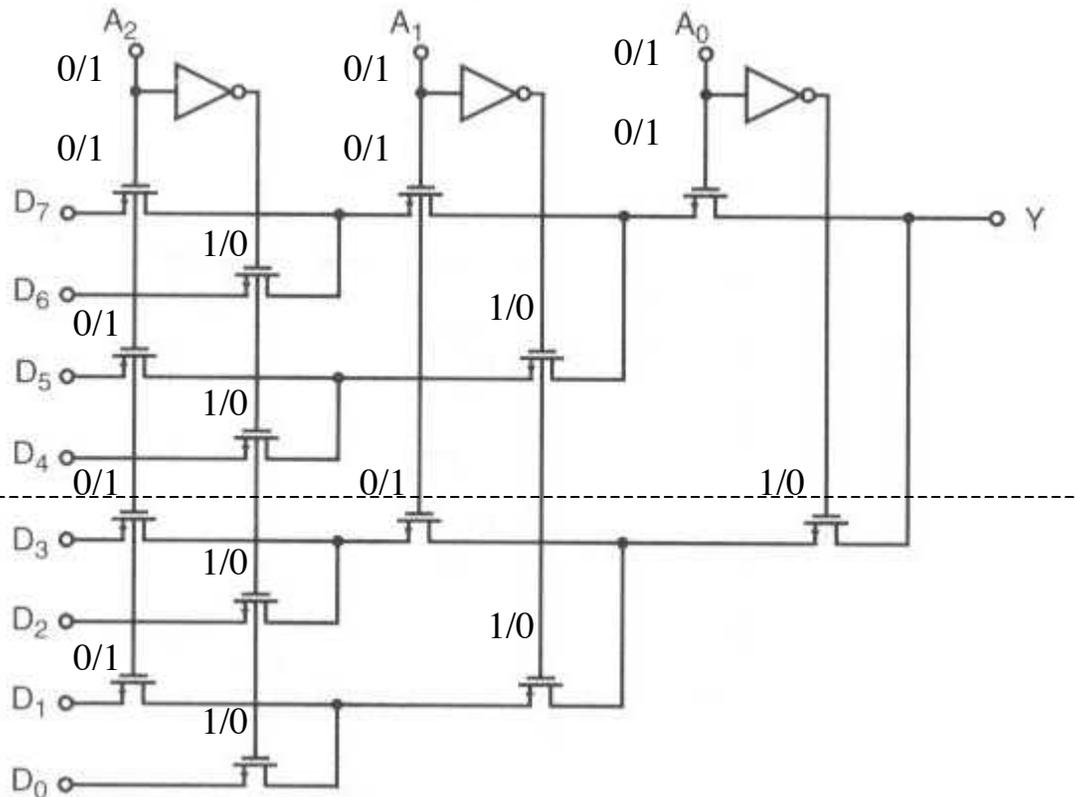
Table 5.1 The Truth Table of the *exclusive-or* Function

A	B	C
0	0	0
0	1	1
1	0	1
1	1	0

XOR	NMOS X-Gate	pseudo-NMOS traditional	CMOS X-Gate	CMOS traditional
	6	7	8	10

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Transmission Gate 8-to-1 MUX (Martin, c5.1)



A_2	A_1	A_0	Y
0	0	0	D_0
0	0	1	D_4
0	1	0	D_2
0	1	1	D_6
1	0	0	D_1
1	0	1	D_5
1	1	0	D_3
1	1	1	D_7
(E / O)	(T / B)	(D_0 - D_3), (D_4 - D_7)	

Typically, one would not use more than 8-to-1 MUX. Why?

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Transmission Gate Clocked Latch (Martin, c5.1)

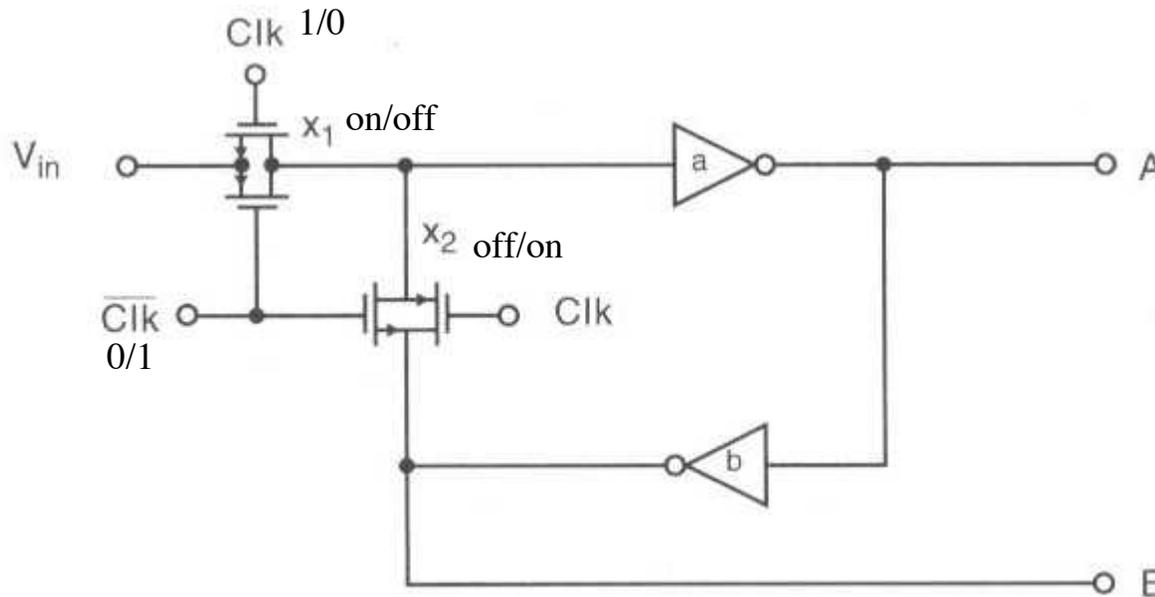
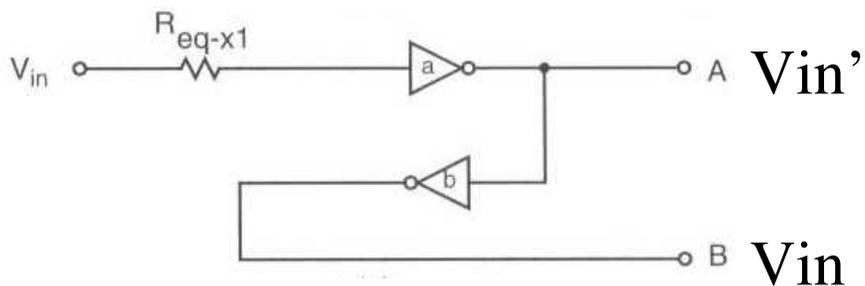


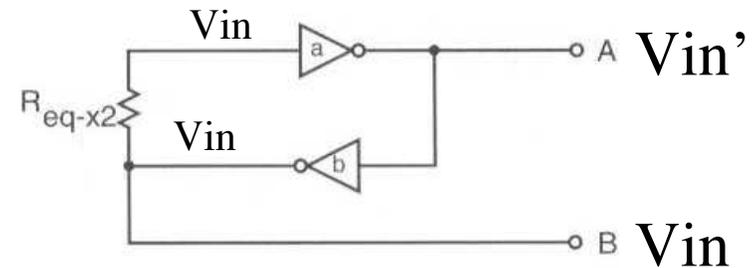
Figure 5.6 A transmission-gate-based clocked latch.

When CLK is high:



“track mode”, latch is loaded

When CLK is low:

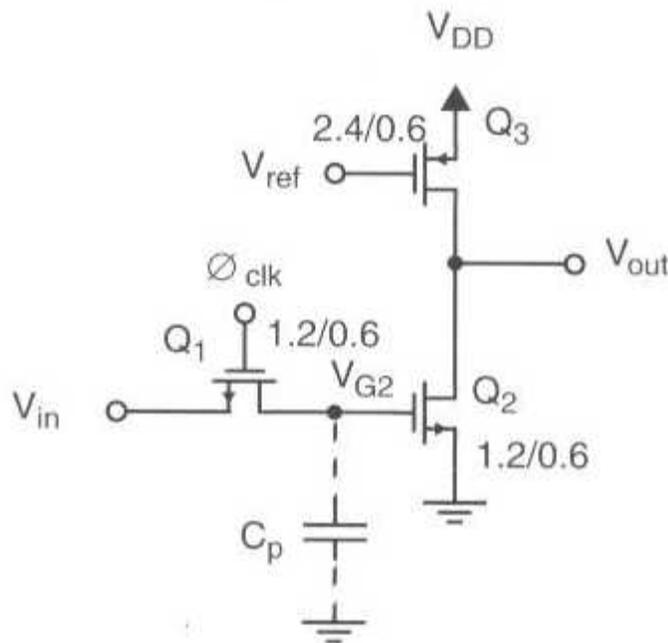


data is latched to Vin at time of clock transition

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Voltage Drop of n-CH X-Gates (Martin, c5.1)

Pseudo-NMOS X-Gate
delay line cell



Desired operation:

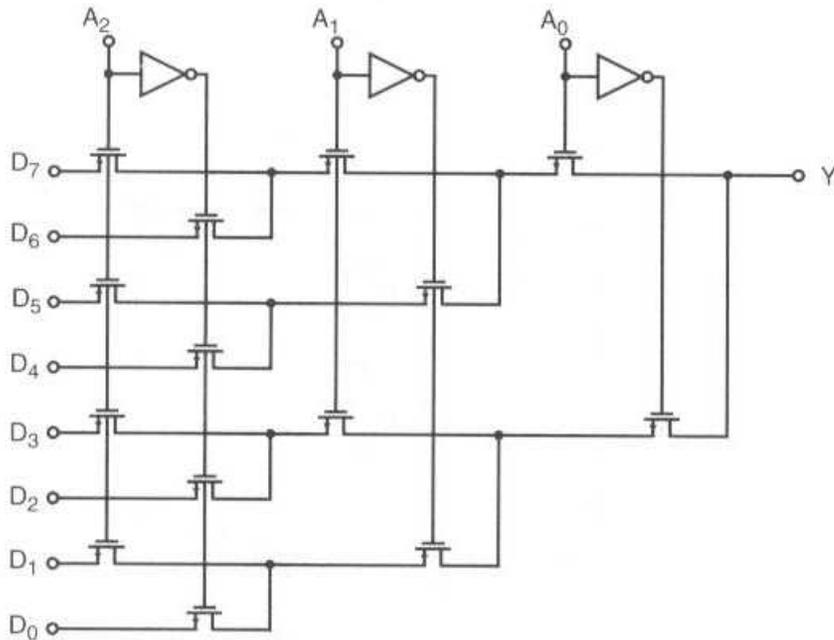
- Start with $\phi_{\text{clk}} = 1$, $V_{G2} = V_{\text{in}}$
- Transition, $\phi_{\text{clk}} 1 \rightarrow 0$, Q1 on \rightarrow off, C_p keeps voltage
- AKA source follower or common drain buffer
- C_p is due to what?
- $V_{\text{out}} = V_{\text{in}}$

Problems with circuit:

- Start with $V_{\text{in}} = 0$, and $\phi_{\text{clk}} 0 \rightarrow 1$
- $V_{G2} = V_{\text{in}} = 0\text{V}$, so Q1 S/D are at ground (Q1 is in what region?)
- If $V_{\text{in}} \rightarrow V_{\text{DD}}$, while $\phi_{\text{clk}} = 1$, initially LHS of Q1 is drain
RHS is the source, and $V_{\text{gs}} = V_{\text{DD}}$, and $V_{\text{gd}} = 0$
(Q1 is in what region?)
- V_{G2} charges up to $V_{\text{DD}} - V_{\text{tn}}$
- V_{eff} for Q1 will become zero ($V_{\text{gs}} - V_{\text{tn}} = 0$)
- Q1 shuts off when $V_{\text{gs}} = V_{\text{tn}}$, or when $V_{G2} = V_{\text{DD}} - V_{\text{tn}}$
- Thus V_{G2} never gets to V_{DD} , and body effect determines
how far from V_{DD} the node ends up
- As body effect goes up, V_{tn} goes up, V_{G2} goes down
- So what is the problem?

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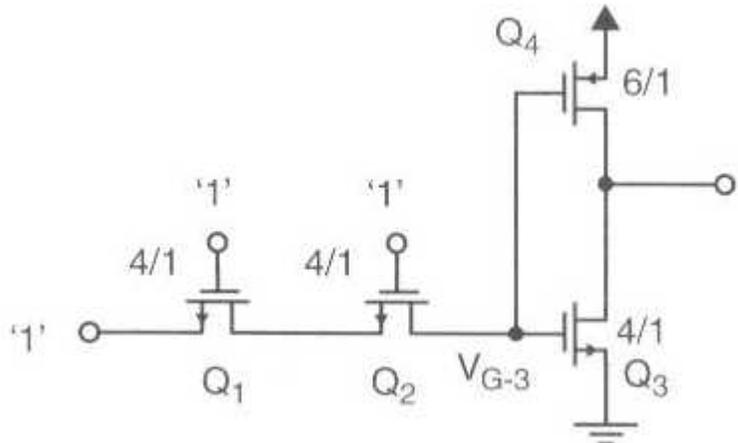
Voltage Drop of n-CH X-Gates (Martin, c5.1)



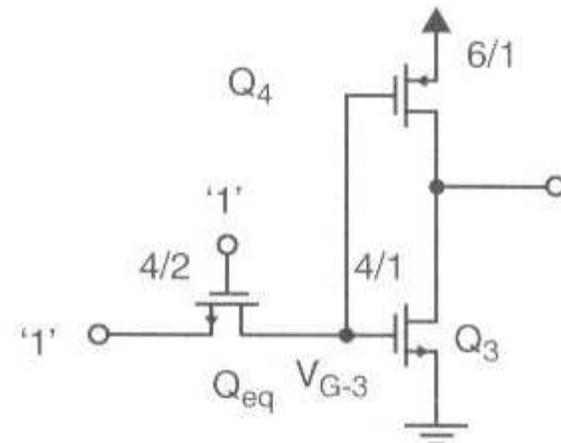
Through how many series transistors does the data pass?

- Equivalency says that two series transistors with W/L is the same as one transistor with $W/2L$

- Voltage at gate of Q_3 is the same, it just takes longer to rise

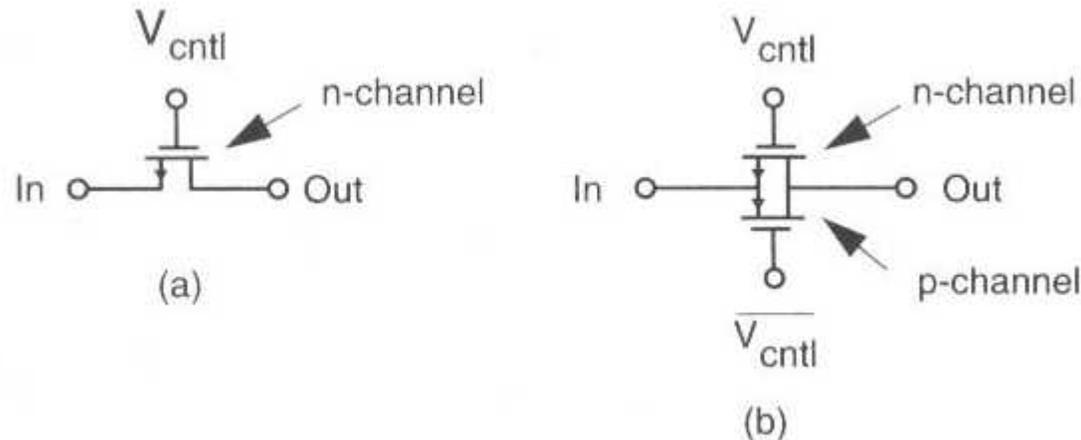


\Rightarrow



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n-CH vs. CMOS X-Gates (Martin, c5.1)



- Area may be smaller if NMOS used vs. CMOS
- CMOS X-Gates transfer “1” and “0” efficiently. Why?
- CMOS X-Gates ████ faster in 0->1 transition. Why?
- N-CH voltage drop a major disadvantage, but can be eliminated

Speed:

- When junction capacitance dominates, which should be used?
- When load capacitance dominates, which should be used?

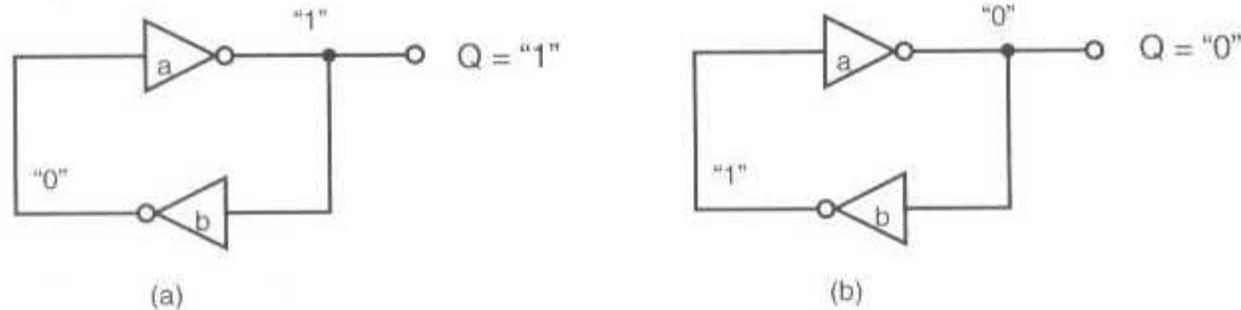
Power:

- Which is more sensitive to V_t value?

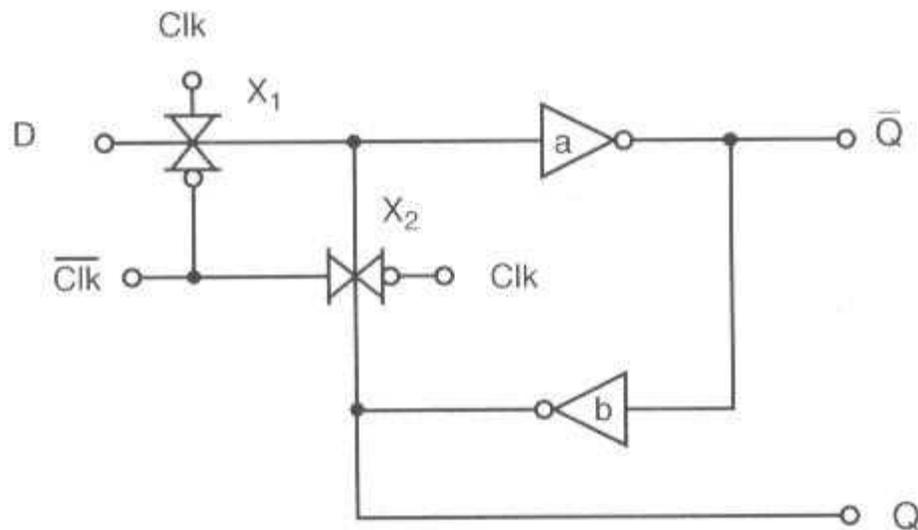
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Static CMOS Digital Latches (Martin, c7.1)

Example of a two cross coupled inverters, having positive feedback:

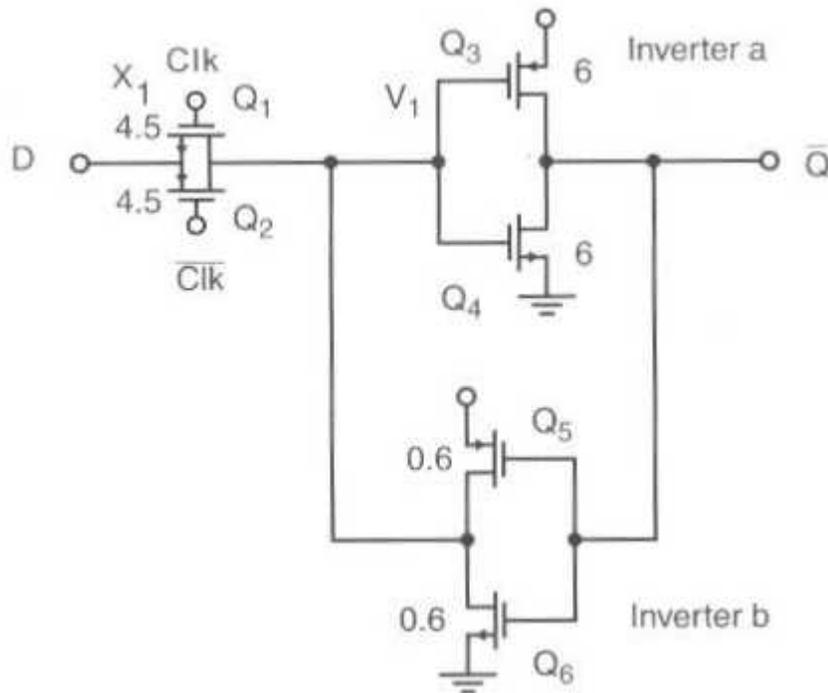


Latch realized below using what type of logic?



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Static CMOS Digital Latches (Martin, c7.1)



- What has changed from previous slide for latch?

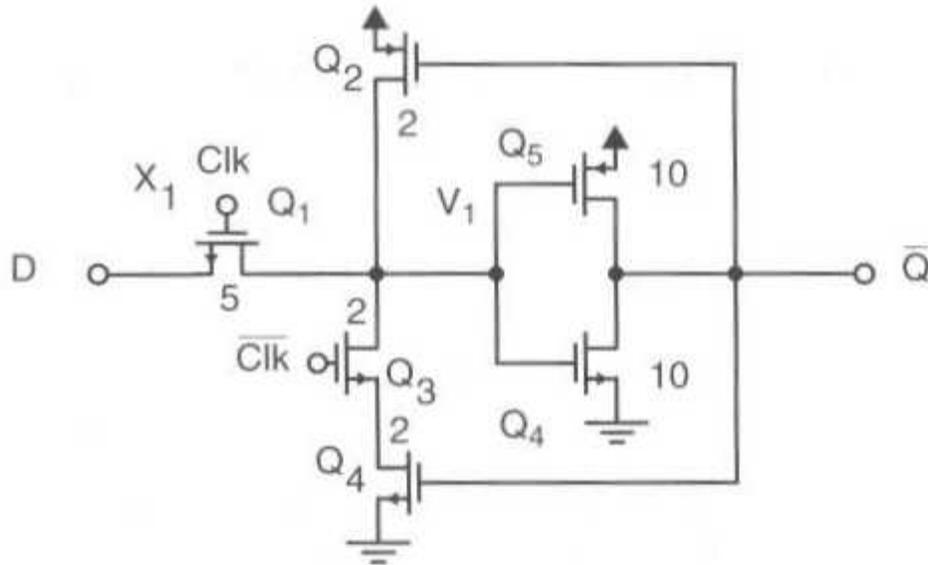
- When CLK is high, D is passed to V1, but why is it not inverted by Q5/Q6?

Good: hysteresis is added, noise immunity for slow-moving signals, less area than latch of previous foil

Bad: Only inverter a is a driver. Why?

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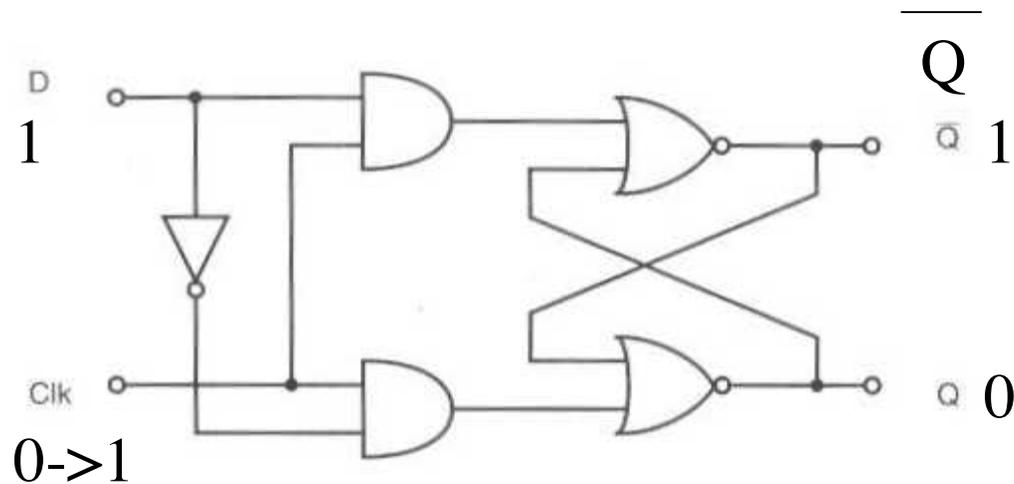
Static CMOS Digital Latches (Martin, c7.1)



- Q1 is used as a pass transistor, so why is Q2 in the circuit?
- Q2 ratio W/L should be small or large compared to Q1?
- When CLK is low, Q3 is on, reinforcing a stored “0” at V1.
- What reinforces the stored “1” at V1 when CLK is low?

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Static CMOS Digital Latches (Martin, c7.1)



- Cross coupled NOR gates
- $Q=D$ when $Clk=1$
- Q preserved when $Clk=0$

- As CLK $0 \rightarrow 1$, $Q' \rightarrow gnd$ if Q_5/Q_7 widths are larger than Q_3
- Q_5 series with Q_7 gives what width?
- Compare to what width of Q_3 ?
- When Q' is low, Q_4 is on, Q_2 off, Q is 1
- This means one inverter delay

